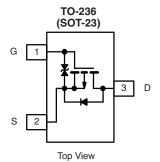




## P-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY								
V <sub>DS</sub> (V)	$R_{DS(on)}(\Omega)$	V <sub>GS(th)</sub> (V)	I <sub>D</sub> (mA)	Q <sub>g</sub> (Typ.)				
- 30	1.4 at V <sub>GS</sub> = - 10 V	- 1.3 to - 3.0	- 385	1000				
	$3.5$ at $V_{GS} = -4.5$ V	- 1.3 to - 3.0	- 240	1000				



Marking Code: 2K*wll*2K = Part Number Code for TP0202K *w* = Week Code *ll* = Lot Traceability

Ordering Information: TP0202K-T1-E3 (Lead (Pb)-free)

TP0202K-T1-GE3 (Lead (Pb)-free and Halogen-free)

#### **FEATURES**

 Halogen-free According to IEC 61249-2-21 Available



High-Side Switching

• Low On-Resistance: 1.2  $\Omega$  (typ.)

• Low Threshold: - 2 V (typ.)

Fast Swtiching Speed: 14 ns (typ.)Low Input Capacitance: 31 pF (typ.)

2000 V ESD Protection

#### **APPLICATIONS**

- Drivers: Relays, Solenoids, Lamps, Hammers, Display, Memories, Transistors, etc.
- · Battery Operated Systems
- Power Supply Converter Circuits
- Solid-State Relays

#### **BENEFITS**

- · Ease in Driving Switches
- Low Offset (Error) Voltage
- · Low-Voltage Operation
- High-Speed Circuits
- · Easily Driven without Buffer

ABSOLUTE MAXIMUM RATINGS T <sub>A</sub> = 25 °C, unless otherwise noted							
Parameter	Symbol	Limit	Unit				
Drain-Source Voltage		$V_{DS}$	- 30	V			
Gate-Source Voltage		V <sub>GS</sub>	± 20	V			
Continuous Drain Current /T 150 °C\a	T <sub>A</sub> = 25 °C	l <sub>D</sub>	- 385	mA			
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 85 °C	Ο	- 280				
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	- 750				
Davis Dischartis al	T <sub>A</sub> = 25 °C	P <sub>D</sub>	350	mW			
Power Dissipation <sup>a</sup>	T <sub>A</sub> = 85 °C	гD	185	IIIVV			
Maximum Junction-to-Ambient <sup>a</sup>		R <sub>thJA</sub>	350	°C/W			
Operating Junction and Storage Temperature Range	T <sub>J,</sub> T <sub>stg</sub>	- 55 to 150	°C				

#### Notes:

- a. Surface Mounted on FR4 board.
- b. Pulse width limited by maximum junction temperature.

ROHS
COMPLIANT
HALOGEN
FREE

## **TP0202K**

# Vishay Siliconix



SPECIFICATIONS T <sub>A</sub> = 25 °C, unless otherwise noted									
,,	Symbol	Test Conditions	Limits						
Parameter			Min.	Тур.	Max.	Unit			
Static									
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{GS} = 0 \text{ V}, I_D = -100 \mu\text{A}$	- 30	- 38		V			
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 1.3	- 2	- 3.0	\ \ \			
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 5 \text{ V}$			± 50	nA			
Gate-body Leakage		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 10 \text{ V}$			± 300				
Zara Cata Valtaga Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = - 30 V, V <sub>GS</sub> = 0 V			- 100				
Zero Gate Voltage Drain Current		V <sub>DS</sub> = - 30 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 85 °C			- 10	μΑ			
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>GS</sub> = - 10 V, V <sub>DS</sub> = - 10 V	- 500			mA			
	R <sub>DS(on)</sub>	$V_{GS} = -4.5 \text{ V}, I_D = -50 \text{ mA}$		2.1	3.5	Ω			
Drain-Source On-Resistance <sup>a</sup>		V <sub>GS</sub> = - 10 V, I <sub>D</sub> = - 500 mA		1.25	1.4				
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 5 V, I <sub>D</sub> = - 200 mA		315		mS			
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>S</sub> = - 250 mA, V <sub>GS</sub> = 0 V			- 1.2	V			
Dynamic		,	1						
Total Gate Charge	Qg	V 10 V V 10 V		1000		pC			
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = -16 \text{ V}, V_{GS} = -10 \text{ V}$ $I_{D} \cong -200 \text{ mA}$		225					
Gate-Drain Charge	Q <sub>gd</sub>	1D = - 200 mA		175					
Input Capacitance	C <sub>iss</sub>	V 45VV 6V		31		pF			
Output Capacitance	C <sub>oss</sub>	$V_{DS} = -15 \text{ V}, V_{GS} = 0 \text{ V}$ f = 1 MHz		11					
Reverse Transfer Capacitance	C <sub>rss</sub>	1 – 1 1/11/12		4					
Switching <sup>b</sup>									
Turn-On Time	t <sub>d(on)</sub>			9		- ns			
Turn-On Time	t <sub>r</sub>	$V_{DD} = -15 \text{ V}, R_{L} = 75 \Omega$		6					
Turn-Off Time	t <sub>d(off)</sub>	$I_D \cong$ - 200 mA, $V_{GEN}$ = - 10 V, $R_G$ = 6 $\Omega$		30					
ium-on fille	t <sub>f</sub>			20					

#### Notes:

- a. Pulse test: PW  $\leq$  300  $\mu s$  duty cycle  $\leq$  2 %.
- b. Switching time is essentially independent of operating temperature.

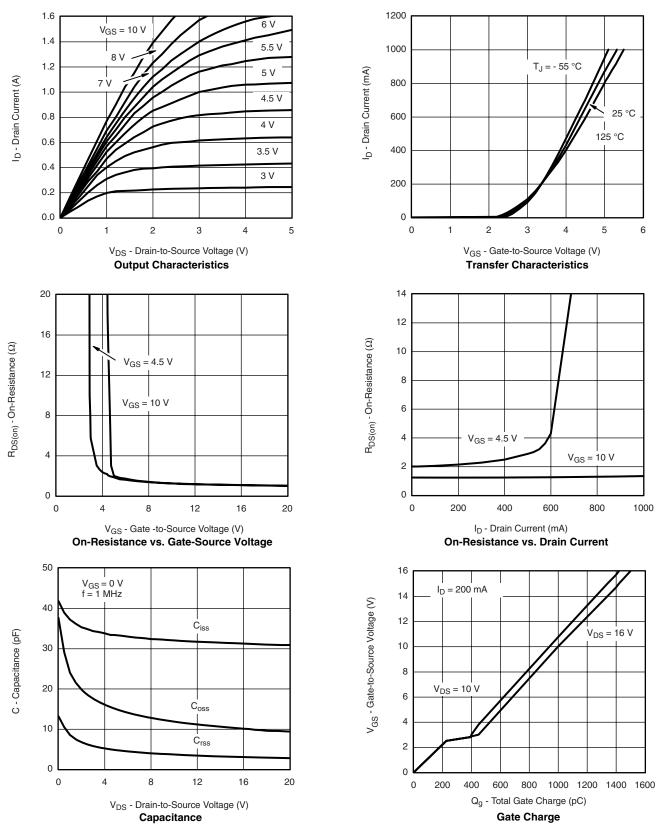
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.







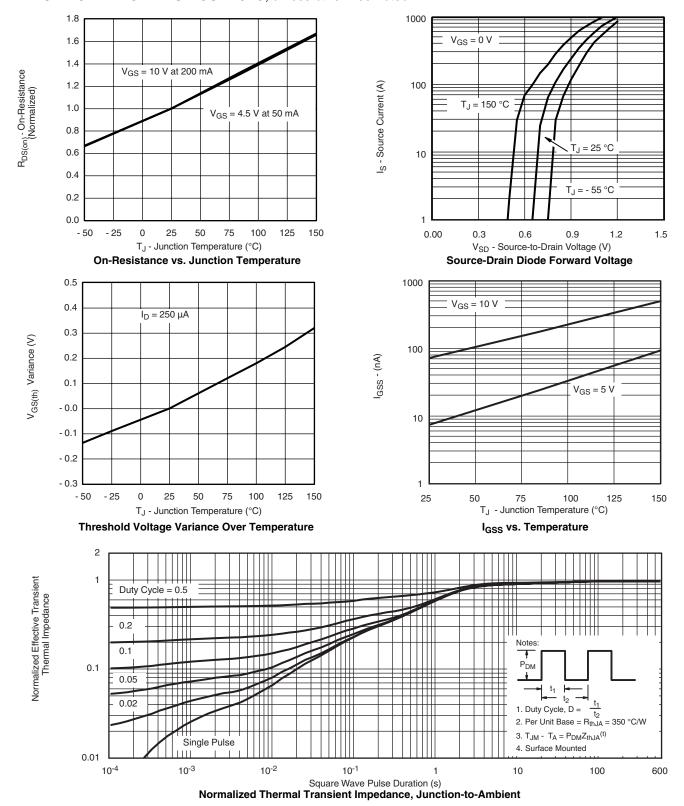
### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



## Vishay Siliconix



### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="https://www.vishay.com/ppg?71609">www.vishay.com/ppg?71609</a>.



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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

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